

UNISONIC TECHNOLOGIES CO., LTD

7N90-MK6 Preliminary Power MOSFET

7A, 900V N-CHANNEL POWER MOSFET

■ DESCRIPTION

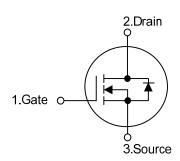
The UTC **7N90-MK6** is an N-channel mode power MOSFET using UTC's advanced technology to provide costumers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC **7N90-MK6** is universally applied in active power factor correction, electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.



- * High switching speed
- * $R_{DS(ON)}$ <2.20 @ V_{GS} =10V, I_{D} =3.5A
- * 100% avalanche tested
- * Improved dv/dt capability

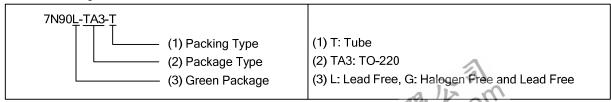
■ SYMBOL



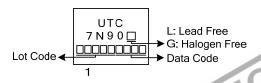
■ ORDERING INFORMATION

Ordering Number		Doolsons	Pin Assignment			Deeking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
7N90L-TA3-T	7N90G-TA3-T	TO-220	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



■ MARKING



1 TO-220

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ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V_{DSS}	900	V
Gate to Source Voltage		V_{GSS}	±30	V
Continuous Drain Current	T _C =25°C		7.0	Α
	T _C =100°C	I _D	4.4	Α
Pulsed Drain Current (Note 2)		I_{DM}	28	Α
Peak Diode Recovery dv/dt (Note 3)		dv/dt	4.0	V/ns
Power Dissipation		P_D	52	W
Junction Temperature		T_J	+150	Ŝ
Storage Temperature		T _{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature
- 3. $I_{SD} \le 7.0A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ _{JC}	2.4	°C/W	

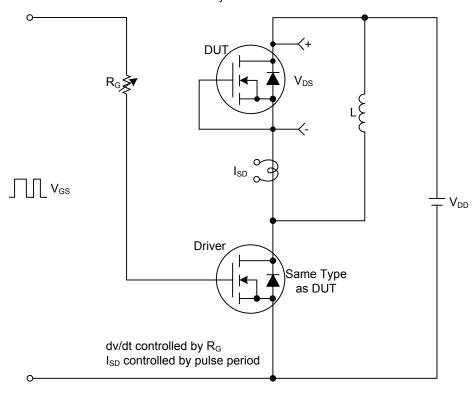
ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

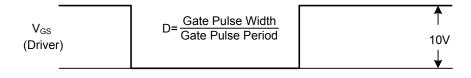
PARAMETER		SYMBOL	TEST CONDITIONS MIN		TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250μA 900				V
Breakdown Voltage Temperature	e Coefficient		•		0.96		V/°C
Drain-Source Leakage Current		I _{DSS}	V _{DS} =900V, V _{GS} =0V			10	μA
			V _{DS} =720V, T _C =125°C			100	μA
Gate-Source Leakage Current	Forward	I _{GSS}	V _{DS} =0V ,V _{GS} =30V			100	nA
	Reverse	I _{GSS}	V _{DS} =0V ,V _{GS} =-30V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	3.0		5.0	V
Drain-Source On-State Resistan	ce	R _{DS(ON)}	V _{GS} =10V, I _D =3.5A		1.8	2.2	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}	V _{DS} =25V,V _{GS} =0V, f=1.0MHz		1450	1880	pF
Output Capacitance		Coss			115	140	pF
Reverse Transfer Capacitance		C _{RSS}			95	110	pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		t _{D(ON)}			90		ns
Turn-ON Rise Time		t _R	V_{DD} =30V, I_{D} =0.5A,		56		ns
Turn-OFF Delay Time		t _{D(OFF)}	R _G =25Ω (Note 4,5)		138		ns
Turn-OFF Fall Time		t _F			34		ns
SOURCE- DRAIN DIODE RATII	NGS AND CI	HARACTERI	STICS				
Maximum Body-Diode Continuo	us Current	Is	6			7	Α
Maximum Body-Diode Pulsed Co	urrent	I _{SM}	~ >	7		28	Α
Drain-Source Diode Forward Vo	ltage	V_{SD}	I _S =7.0A, V _{GS} =0V	U		1.4	V
Notes: 1. Pulse Test : Pulse widt 2. Essentially independer	th ≤ 300µs, D nt of operatin	outy cycle ≤ 2 g temperatur	% e				
	/4	C WY	I _S =7.0A, V _{GS} =0V				
UNISONIC TECHNOLOGIES CO., LTD www.unisonic.com.tw				2 of 5 QW-R205-049.a			

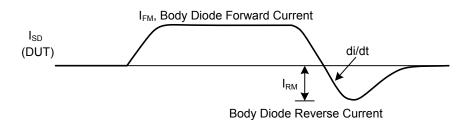


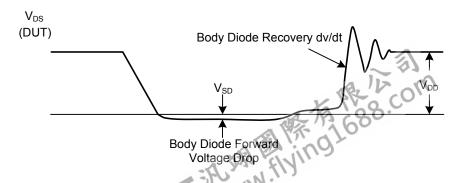
TEST CIRCUITS AND WAVEFORMS

Peak Diode Recovery dv/dt Test Circuit & Waveforms

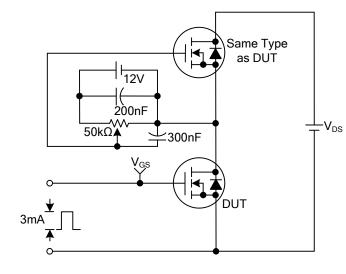




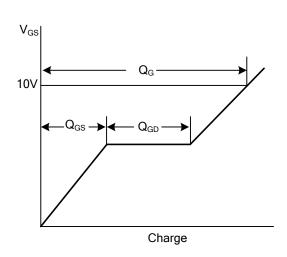




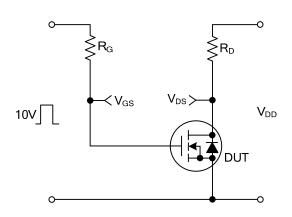
TEST CIRCUITS AND WAVEFORMS(Cont.)



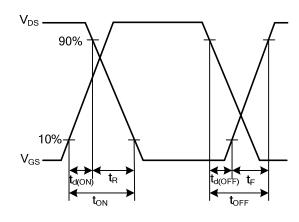
Gate Charge Test Circuit



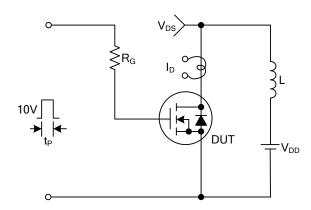
Gate Charge Waveforms



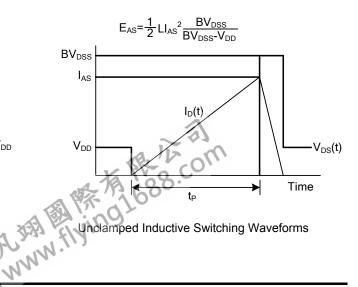
Resistive Switching Test Circuit



Resistive Switching Waveforms



Unclamped Inductive Switching Test Circuit



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